1. General description

NPN/NPN Resistor-Equipped Transistor (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Low package height of 0.37 mm
- · Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replaces general-purpose transistors in digital applications
- · Mobile applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	

[1] See section "Test information" for resistor calculation and test conditions.



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	1 7 6	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2	2 5	TR2
5	12	input (base) TR2	3 8 4	R2 R1
6	01	output (collector) TR1		
7	01	output (collector) TR1	Transparent top view	
8	O2	output (collector) TR2	DFN1010B-6 (SOT1216)	GND1 I1 O2 aaa-019894

6. Ordering information

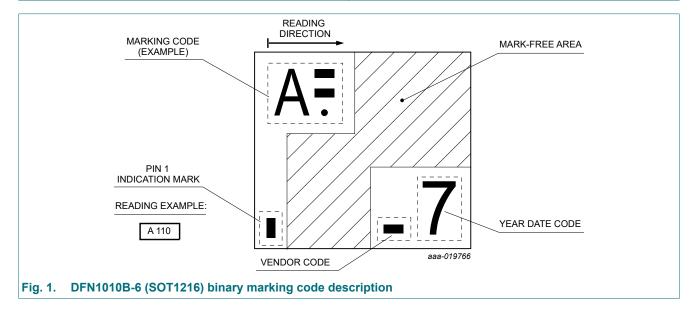
Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PQMH13-Q		plastic, leadless thermal enhanced ultra thin small outline package; 6 terminals; 0.35 mm pitch; 1.1 mm x 1 mm x 0.37 mm body	SOT1216

7. Marking

Table 4. Marking codes

Type number	Marking code
PQMH13-Q	A
	100



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

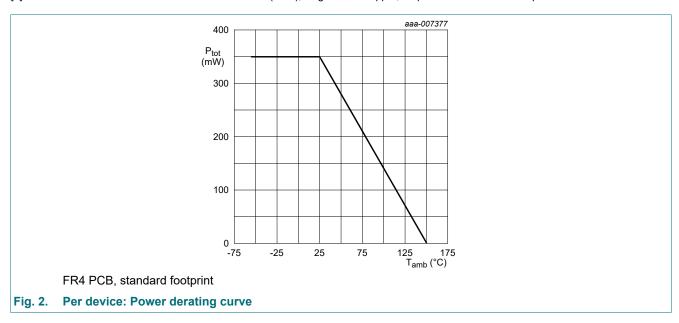
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'			
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
V _I	input voltage			-5	30	V
Io	output current			-	100	mA
I _{CM}	peak collector current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device			'	'		'
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

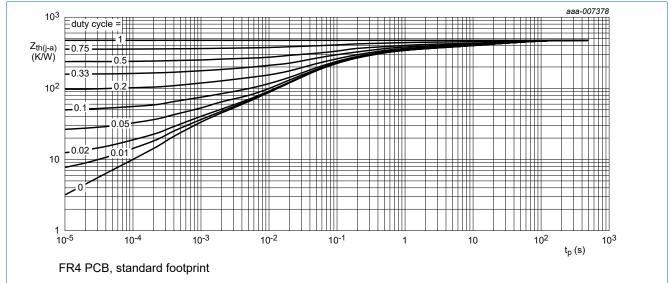


Fig. 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

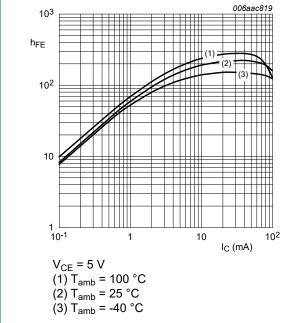
NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		50	-	-	V
I _{CBO}	collector-base cut-off current			-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	170	μΑ
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	c = 5 mA; I _B = 0.25 mA; T _{amb} = 25 °C		-	-	100	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	0.6	0.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 5 mA; T _{amb} = 25 °C		1.3	0.9	-	V
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor

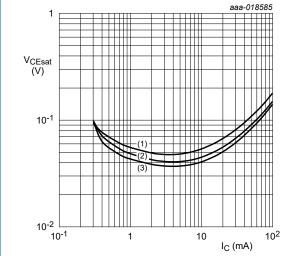


aaa-018581 0.1 0.63 mA 0.70 m/ I_C (A) 0.56 mA 0.08 0.49 mA 0.42 mA 0.35 mA 0.06 0.28 mA -0.21 mA 0.04 0.14 mA 0.02 I_B = 0.07 mA 4 V_{CE} (V) 2 3 T_{amb} = 25 °C

Fig. 5. Collector current as a function of collectoremitter voltage; typical values

PQMH13-C

NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

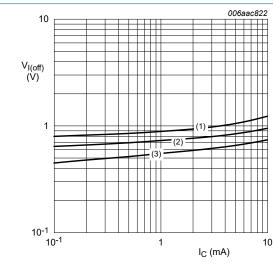


$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 ° ($$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



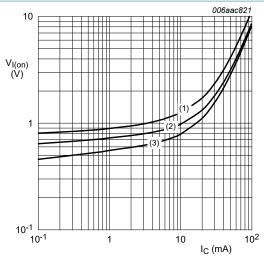
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \,^{\circ}\text{C}$$

(2) $T_{amb} = 25 \,^{\circ}\text{C}$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 8. Off-state input voltage as a function of collector current; typical values

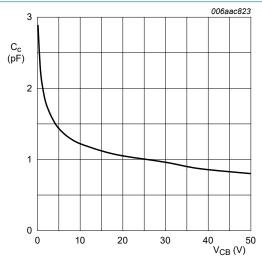


$$V_{CF} = 0.3 \text{ V}$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

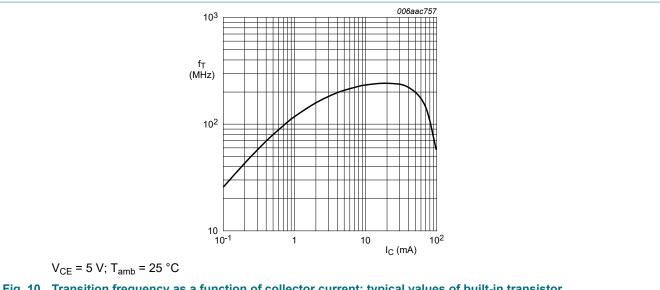
Fig. 7. On-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

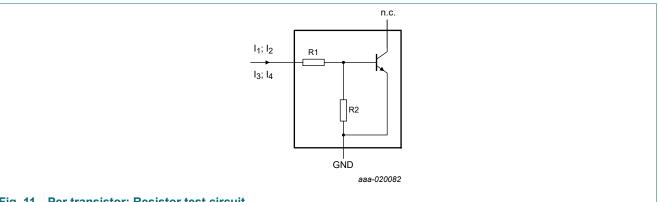


Fig. 11. Per transistor: Resistor test circuit

Resistor test conditions

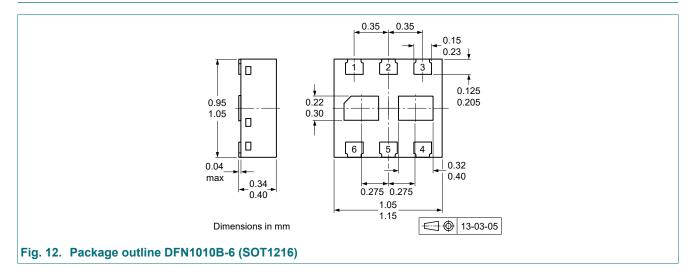
Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PQMH13-Q	4.7	47	90 μΑ	140 µA	-55 µA	-105 µA

PQMH13-Q

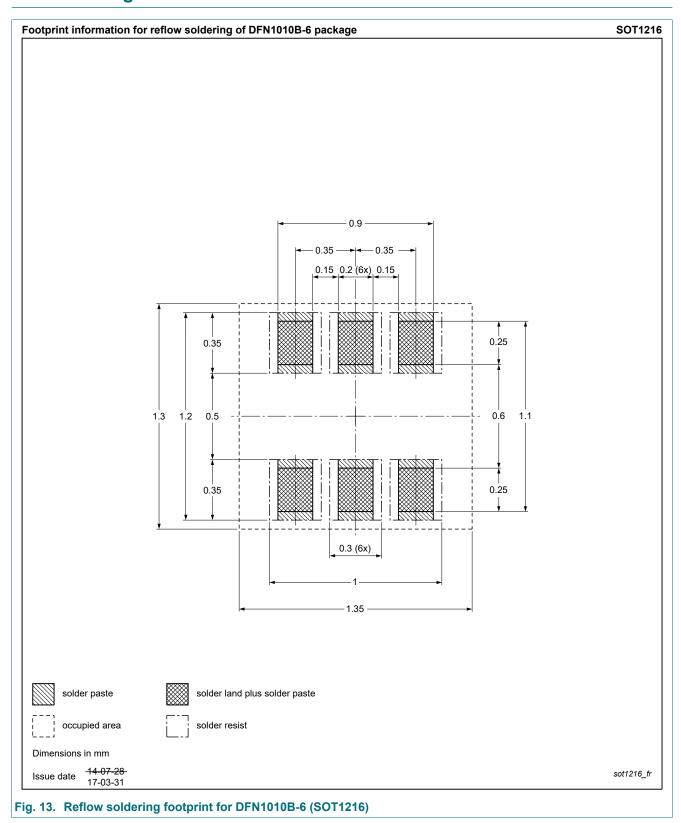
NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

12. Package outline



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

13. Soldering



NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PQMH13-Q v.1	20230713	Product data sheet	-	-

NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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NPN/NPN resistor-equipped double transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

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